



CHENMKO ENTERPRISE CO.,LTD

CH0420LPT

Lead free devices

SURFACE MOUNT
SCHOTTKY BARRIER DIODE
VOLTAGE 20 Volts CURRENT 0.4 Ampere

APPLICATION

- * Low power rectification

FEATURE

- * Small surface mounting type. (SOT-23)
- * Two diode with common cathode for excellent.
- * High reliability

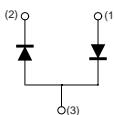
CONSTRUCTION

- * Silicon epitaxial planar

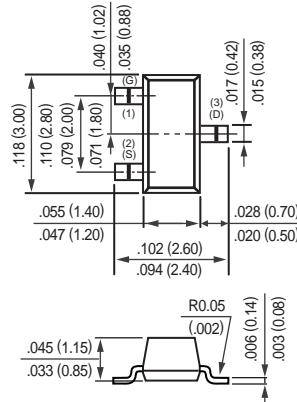
MARKING

- * B8

CIRCUIT



SOT-23



Dimensions in millimeters

SOT-23

MAXIMUM RATINGS (At TA = 25°C unless otherwise noted)

RATINGS	SYMBOL	CH0420LPT	UNITS
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	20	Volts
Maximum RMS Voltage	V _{RMS}	14	Volts
Maximum DC Blocking Voltage	V _{DC}	20	Volts
Maximum Average Forward Rectified Current	I _o	0.4	Amps
Peak Forward Surge Current at 8.3 mSec single half sine-wave	I _{FSM}	2.0	Amps
Typical Junction Capacitance between Terminal (Note 1)	C _J	170	pF
Maximum Operating Temperature Range	T _J	+125	°C
Storage Temperature Range	T _{STG}	-55 to +125	°C

ELECTRICAL CHARACTERISTICS (At TA = 25°C unless otherwise noted)

CHARACTERISTICS	SYMBOL	CH0420LPT	UNITS
Maximum Instantaneous Forward Voltage at I _{F(1)} = 100mA	V _{F(1)}	0.31	Volts
Maximum Instantaneous Forward Voltage at I _{F(2)} = 500mA	V _{F(2)}	0.43	Volts
Maximum Average Reverse Current at V _R = 10V	I _{R(1)}	100	uAmps
Maximum Average Reverse Current at V _R = 20V	I _{R(2)}	250	uAmps

NOTES : 1. Measured at 1.0 MHz and applied reverse voltage of 0 volts.

2. ESD sensitive product handling required.

2004-06

RATING CHARACTERISTIC CURVES (CH0420LPT)

FIG. 1 - FORWARD CURRENT DERATING CURVE

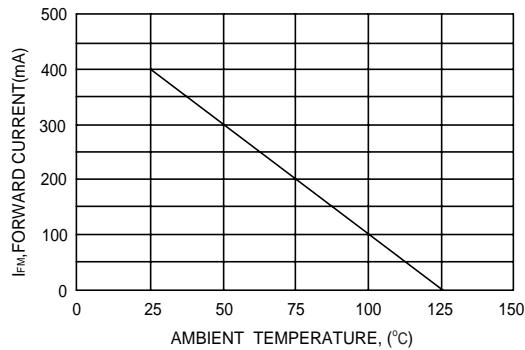


FIG. 2 - FORWARD CHARACTERISTICS

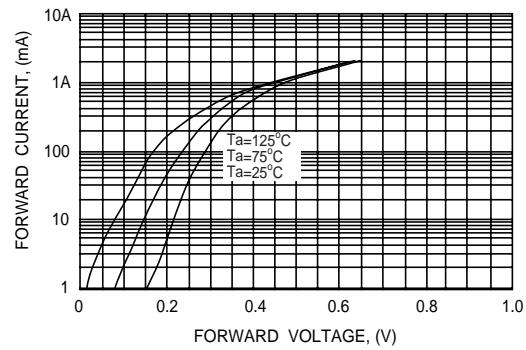


FIG. 3 - REVERSE CHARACTERISTICS

